











LMV722-Q1

SLOS969 - JUNE 2017

LMV722-Q1 10-MHz Low-Noise, Low-Voltage Operational Amplifier

Features

- **Qualified for Automotive Applications**
- AEC-Q100 Qualified With the Following Results:
 - **Device Ambient Operating Temperature:** -40°C to +125°C
 - Device HBM ESD Classification Level 2
 - Device CDM ESD Classification Level C1
- Power-Supply Voltage Range: 2.2 V to 5.5 V
- Low Supply Current: 905 μ A/Amplifier at 2.2 V
- High Unity-Gain Bandwidth: 10 MHz
- Rail-to-Rail Output Swing
 - 600-Ω Load: 120 mV From Either Rail at 2.2 V
 - 2-kΩ Load: 50 mV From Either Rail at 2.2 V
- Input Common-Mode Voltage Range Includes
- Input Voltage Noise: 10.5 nV/ \sqrt{Hz} at f = 1 kHz

Applications

- Infotainment
- **Engine Control Unit**
- Automotive Lighting
- Audio Signal Path

3 Description

The LMV722-Q1 device is a low-noise, low-voltage operational amplifier (op amp) that can be designed into a wide range of applications. The LMV722-Q1 has a unity-gain bandwidth of 10 MHz, slew rate of 5.25 V/µs, and good voltage and current noise performance.

The LMV722-Q1 is designed to provide optimal performance in low-voltage and low-noise systems such audio signal path or motor control applications. The device provides rail-to-rail output swing into heavy loads. The input common-mode voltage range includes ground and the maximum input offset voltage is 3.5 mV (over recommended temperature range) for the device. The capacitive load capability is also good at low supply voltages. The operating range is from 2.2 V to 5.5 V.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
LMV722-Q1	VSSOP	3.00 mm × 4.90 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic

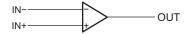






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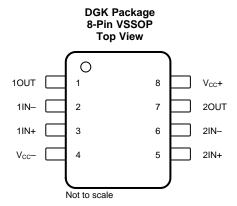
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4 Revision History

DATE	REVISION	NOTES
June 2017	*	Initial release.

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5 Pin Configuration and Functions



Pin Functions

	· ··· · directions									
PIN		1/0	DESCRIPTION							
NO.	NAME	1/0	DESCRIPTION							
1	1OUT	0	Output of amplifier 1							
2	1IN-	1	Inverting input of amplifier 1							
3	1IN+	1	Non-inverting input of amplifier 1							
4	V _{CC} -	1	Negative power supply							
5	2IN+	1	Non-inverting input of amplifier 2							
6	2IN-	1	Inverting input of amplifier 2							
7	2OUT	0	Output of amplifier 2							
8	V _{CC} +	1	Positive power supply							
6 7	2IN- 2OUT	0 I	Inverting input of amplifier 2 Output of amplifier 2							

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V _{CC+} - V _{CC-}	Supply voltage ⁽²⁾		6	V
V _{ID}	Differential input voltage (3)		±Supply voltage	V
T_{J}	Operating virtual-junction temperature		150	°C
T _{stg}	Storage temperature	-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
V	Clastrostatic discharge	Human-body model (HBM), per AEC Q100-002 ⁽¹⁾	2000	V
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per AEC Q100-011	100	V

⁽¹⁾ AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
$V_{CC+} - V_{CC-}$	Supply voltage	2.2	5.5	V
T_J	Operating ambient temperature	-40	125	°C

6.4 Thermal Information

		LMV722-Q1	
	THERMAL METRIC ⁽¹⁾	DGK (VSSOP)	UNIT
		8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	176.3	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	69.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	97.7	°C/W
ΨЈТ	Junction-to-top characterization parameter	12.7	°C/W
ΨЈВ	Junction-to-board characterization parameter	96.3	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

Product Folder Links: LMV722-Q1

⁽²⁾ All voltage values (except differential voltages and V_{CC} specified for the measurement of I_{OS}) are with respect to the network GND.

³⁾ Differential voltages are at IN+ with respect to IN-.

6.5 Electrical Characteristics V_{CC+} = 2.2 V

 $\underline{V_{\text{CC+}}} = 2.2 \text{ V}, \ V_{\text{CC-}} = \text{GND}, \ V_{\text{ICR}} = V_{\text{CC+}}/2, \ V_{\text{O}} = V_{\text{CC+}}/2, \ \text{and} \ R_{\text{L}} > 1 \ \text{M}\Omega \ \text{(unless otherwise noted)}$

	PARAMETER	TEST CONDITI		MIN	TYP	MAX	UNIT
.,	lanut affact valtage	T _J = 25°C		0.02	3	m)/	
V _{IO}	Input offset voltage	$T_J = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}$			3.5	mV	
TCV _{IO}	Input offset voltage average drift	T _J = 25°C		0.6		μV/°C	
I _{IB}	Input bias current	T _J = 25°C			260		nA
I _{IO}	Input offset current	T _J = 25°C			25		nA
			$T_J = 25^{\circ}C$	70	88		
CMMR	Common-mode rejection ratio	V _{ICR} = 0 V to 1.3 V	T _J = -40°C to +125°C	64			dB
		V 22V+5V	$T_J = 25^{\circ}C$	80	90		
PSRR	Power-supply rejection ratio	$V_{CC+} = 2.2 \text{ V to 5 V},$ $V_{O} = 0, V_{ICR} = 0$	T _J = -40°C to +125°C	70			dB
.,	Land a series and a self-	CMRR ≥ 50 dB	T _J = 25°C		-0.3		
V_{ICR}	Input common-mode voltage	T _J = 25°C	1		1.3		V
		D 000 0	$T_J = 25^{\circ}C$	75	81		
		$R_L = 600 \Omega,$ $V_O = 0.75 \text{ V to 2 V}$	T _J = -40°C to +125°C	70			
A_{VD}	Large-signal voltage gain		T _J = 25°C	75	84		dB
		$R_L = 2 k\Omega,$ $V_O = 0.5 V \text{ to } 2.1 V$	$T_J = -40^{\circ}\text{C to}$ +125°C	70			
			T _J = 25°C	2.090	2.125		
	Output swing	$R_L = 600 \Omega \text{ to } V_{CC+}/2$	$T_J = -40^{\circ}\text{C to} +125^{\circ}\text{C}$	2.065			İ
		T _J = 25°C	T _J = 25°C				.,
		$T_{J} = -40$ °C to +125°C	$T_1 = -40^{\circ}\text{C to } +125^{\circ}\text{C}$				
V_{O}			T _J = 25°C	2.150	2.177		V
		$R_L = 2 k\Omega$ to $V_{CC+}/2$	$T_J = -40^{\circ}\text{C to} +125^{\circ}\text{C}$	2.125			
		T _J = 25°C		0.056	0.080		
		$T_J = -40$ °C to +125°C			0.105		
			$T_J = 25^{\circ}C$	10	14.9		
		Sourcing, $V_O = 0 V$, $V_{IN(diff)} = \pm 0.5 V$	T _J = -40°C to +125°C	5			
lo	Output current	Cirling V 00V	T _J = 25°C	10	17.6		mA
		Sinking, $V_O = 2.2 \text{ V}$, $V_{IN(diff)} = \pm 0.5 \text{ V}$	T _J = -40°C to +125°C	5			
	0	T _J = 25°C	•		1.81	2.4	4
I _{CC}	Supply current	$T_J = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}$				2.6	mA
SR	Slew rate ⁽¹⁾	T _J = 25°C			4.9		V/μs
GBW	Gain bandwidth product	T _J = 25°C			10		MHz
Φ_{m}	Phase margin	T _J = 25°C			67.4		٥
G _m	Gain margin	T _J = 25°C			-9.8		dB
V _n	Input-referred voltage noise	f = 1 kHz	T _J = 25°C		11		nV/√ Hz
I _n	Input-referred current noise	f = 1 kHz	T _J = 25°C		0.3		pA/√ Hz
THD	Total harmonic distortion	$f = 1 \text{ kHz}, \text{ AV} = 1, \\ R_L = 600 \ \Omega, \ V_O = 500 \ \text{mV}_{pp}$	T _J = 25°C		0.004%		

⁽¹⁾ Connected as voltage follower with 1-V step input. Number specified is the slower of the positive and negative slew rate.

STRUMENTS

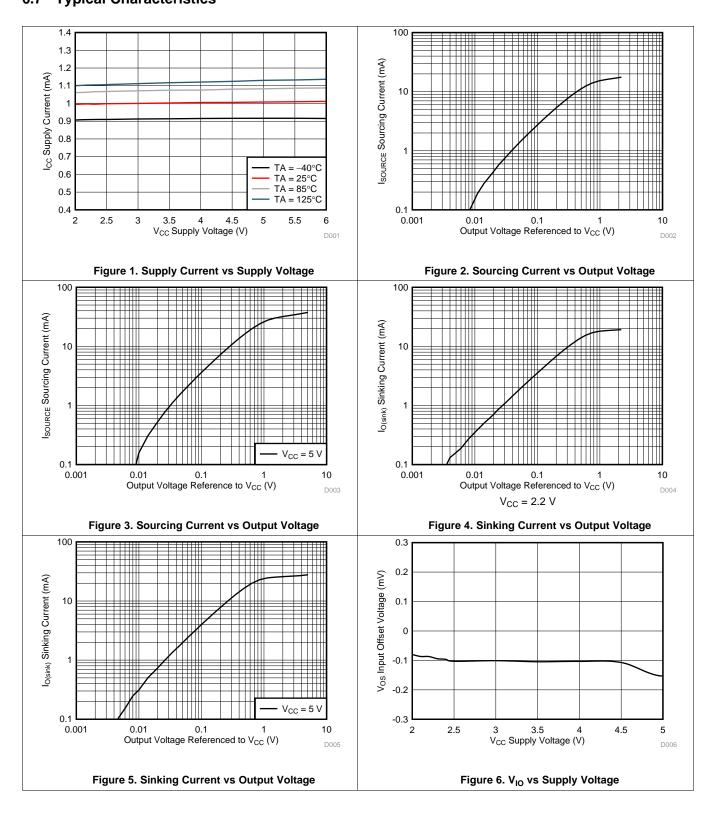
6.6 Electrical Characteristics $V_{CC+} = 5 V$

 V_{CC+} = 5 V, V_{CC-} = GND, V_{ICR} = $V_{CC+}/2$, V_{O} = $V_{CC+}/2$, and R_{L} > 1 M Ω (unless otherwise noted)

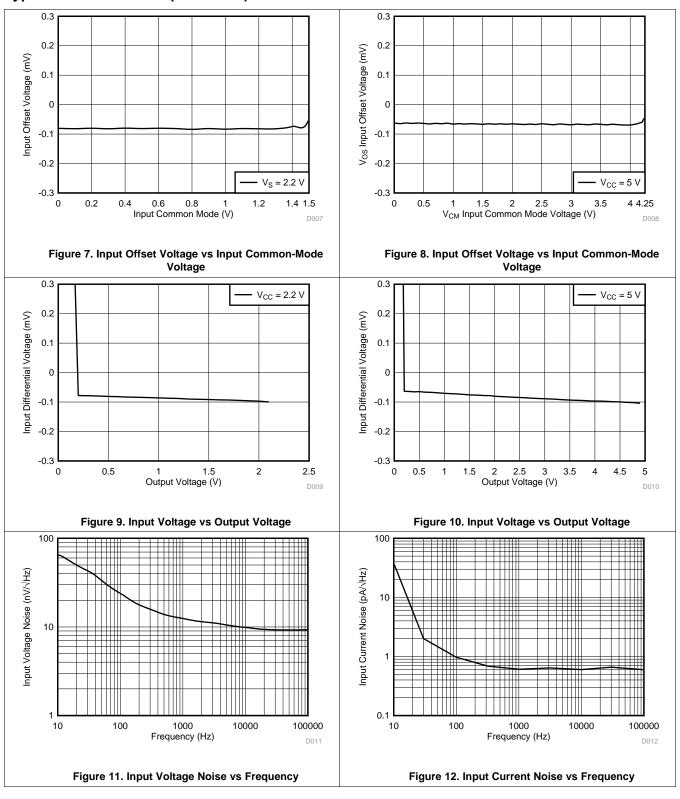
	PARAMETER	TEST CONDIT	IONS	MIN	TYP	MAX	UNIT
.,	Input offset voltage	T _J = 25°C			-0.08	3	m1/
V _{IO} Input offset voltage		$T_{J} = -40^{\circ}\text{C to } +125^{\circ}\text{C}$			3.5	mV	
TCV _{IO}	Input offset voltage average drift	T _J = 25°C			0.6		μV/°C
I _{IB}	Input bias current	T _J = 25°C			260		nA
I _{IO}	Input offset current	T _J = 25°C			25		nA
			T _J = 25°C	80	89		
CMMR	Common-mode rejection ratio	V _{ICR} = 0 V to 4.1 V	$T_J = -40^{\circ}\text{C to} +125^{\circ}\text{C}$	75			dB
•		V 22V455V	$T_J = 25$ °C	70	90		
PSRR	Power-supply rejection ratio	$V_{CC+} = 2.2 \text{ V to 5 V},$ $V_{O} = 0, V_{ICR} = 0$	$T_J = -40^{\circ}\text{C to} +125^{\circ}\text{C}$	64			dB
.,	Land a second second	CMRR ≥ 50 dB	T _J = 25°C		-0.3		
V_{ICR}	Input common-mode voltage	T _J = 25°C			4.1		V
		D 000 0	T _J = 25°C	80	87		
		$R_L = 600 \Omega,$ $V_O = 0.75 \text{ V to } 4.8 \text{ V}$	$T_{J} = -40^{\circ}\text{C to}$ +125°C	70			
A_{VD}	Large-signal voltage gain	5 010	T _J = 25°C	80	94		dB
		$R_L = 2 k\Omega,$ $V_O = 0.7 V \text{ to } 4.9 V$	$T_J = -40^{\circ}\text{C to} +125^{\circ}\text{C}$	70			
			T _J = 25°C	4.84	4.882		
		$R_L = 600 \Omega \text{ to } V_{CC+}/2$	$T_J = -40^{\circ}\text{C to} +125^{\circ}\text{C}$	4.815			
		T _J = 25°C		0.134	0.19	.,	
. ,		$T_{J} = -40^{\circ}\text{C to } +125^{\circ}\text{C}$			0.215		
Vo	Output swing		T _J = 25°C	4.93	4.952		V
		$R_L = 2 k\Omega$ to $V_{CC+}/2$	T _J = -40°C to +125°C	4.905			
		$T_J = 25^{\circ}C$		0.076	0.11		
		$T_{J} = -40^{\circ}\text{C to } +125^{\circ}\text{C}$			0.135		
		0 : 1/ 01/	T _J = 25°C	20	52.6		
	Outset	Sourcing, $V_O = 0 \text{ V}$, $V_{IN(diff)} = \pm 0.5 \text{ V}$	$T_J = -40^{\circ}\text{C to} +125^{\circ}\text{C}$	12			A
lo	Output current	Cipling V 00V	T _J = 25°C	15	23.7		mA
		Sinking, $V_O = 2.2 \text{ V}$, $V_{IN(diff)} = \pm 0.5 \text{ V}$	T _J = -40°C to +125°C	8.5			
	Complex summent	T _J = 25°C	•		2.01	2.4	A
lcc	Supply current	$T_J = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}$				2.8	mA
SR	Slew rate ⁽¹⁾	T _J = 25°C			5.25		V/μs
GBW	Gain bandwidth product	T _J = 25°C			10		MHz
Φ_{m}	Phase margin	T _J = 25°C			72		0
G _m	Gain margin	T _J = 25°C			-11		dB
√ _n	Input-referred voltage noise	f = 1 kHz	T _J = 25°C		10.5		nV/√ Hz
I _n	Input-referred current noise	f = 1 kHz	T _J = 25°C		0.2		pA/√ Hz
THD	Total harmonic distortion	f = 1 kHz, AV = 1, R _L = 600 Ω, V _O = 500 mV _{pp}	T _J = 25°C		0.001%		

⁽¹⁾ Connected as voltage follower with 1-V step input. Number specified is the slower of the positive and negative slew rate.

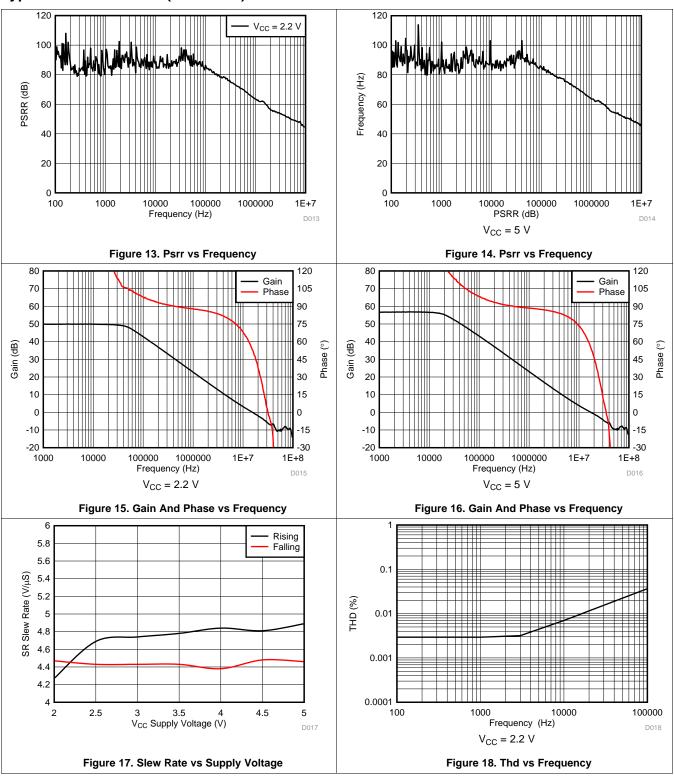
6.7 Typical Characteristics



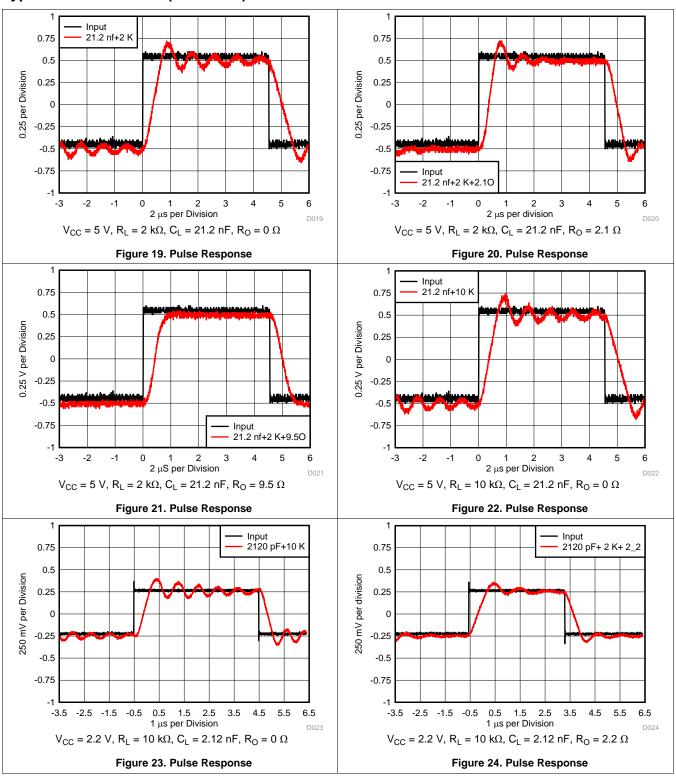
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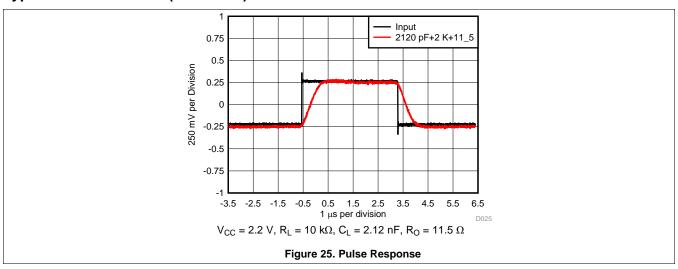




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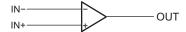
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7 Detailed Description

7.1 Overview

The LMV722-Q1 is a low-power, low-noise, rail-to-rail output op amp. This device is AEC-Q100 qualified for automotive applications. The LMV722-Q1 operates from a single 2.2 V to 5.5 V supply, is unity-gain stable, and is suitable for a wide range of general-purpose applications. The input common-mode voltage range includes ground. Rail-to-rail input and output swing significantly increases dynamic range in low-supply applications and makes applications suitable for driving sampling analog-to-digital converters (ADCs). The small footprints of the LMV722-Q1 package saves space on printed-circuit boards and enables good signal integrity and noise performance during the design of smaller electronic products, such as automotive head units.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Low Noise

The LMV722-Q1 device is a general-purpose op amp that provides low noise of 10.5 nV/√Hz and a wide bandwidth of 10 MHz. The low noise and wide bandwidth make the LMV722-Q1 device attractive for a variety of precision applications that require a good balance between cost and performance.

7.3.2 Rail-to-Rail Output

Rail-to-rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating on low-supply voltages.

7.3.3 Input Includes Ground

This feature allows direct sensing near GND in a single-supply operation.

7.3.4 Signal Integrity

Signals pick up noise between the signal source and the amplifier. By using a physically smaller amplifier package, such as the 8-pin VSSOP (DGK), the LMV722-Q1 can be placed closer to the signal source; reducing noise pickup and increasing signal integrity.

7.4 Device Functional Modes

The only mode available for the LMV722-Q1 device is on.

2



8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The LMV722-Q1 features 10-MHz bandwidth and 5.25-V/ μ s slew rate providing good AC performance at very-low-power consumption. DC applications are well served with a very-low input noise voltage of 10.5 nV / $\sqrt{\text{Hz}}$ at 1 kHz, low input bias current, and a typical input offset voltage of 0.02 mV.

8.2 Typical Application

Figure 26 shows the LMV722-Q1 configured in a low-side current sensing application.

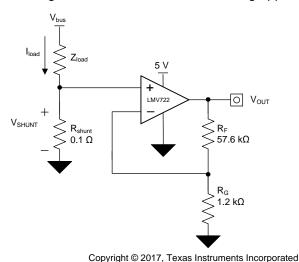


Figure 26. LMV722-Q1 in a Low-Side, Current-Sensing Application

8.2.1 Design Requirements

The design requirements for this design are:

- Load current: 0 A to 1 AOutput voltage: 4.9 V
- Maximum shunt voltage: 100 mV

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Typical Application (continued)

8.2.2 Detailed Design Procedure

The transfer function of the circuit in Figure 26 is given in Equation 1

$$V_{OUT} = I_{LOAD} \times R_{SHUNT} \times Gain$$
 (1)

The load current (I_{LOAD}) produces a voltage drop across the shunt resistor (R_{SHUNT}). The load current is set from 0 A to 1 A. To keep the shunt voltage below 100 mV at maximum load current, the largest shunt resistor is defined using Equation 2.

$$R_{SHUNT} = \frac{V_{SHUNT_MAX}}{I_{LOAD_MAX}} = \frac{100mV}{1A} = 100m\Omega$$
(2)

Using Equation 2, R_{SHUNT} is calculated to be 100 m Ω . The voltage drop produced by I_{LOAD} and R_{SHUNT} is amplified by the LMV722-Q1 to produce an output voltage of roughly 0 V to 4.9 V. The gain needed by the LMV722-Q1 to produce the necessary output voltage is calculated using Equation 3:

$$Gain = \frac{\left(V_{OUT_MAX} - V_{OUT_MIN}\right)}{\left(V_{IN_MAX} - V_{IN_MIN}\right)}$$
(3)

Using Equation 3, the required gain is calculated to be 49 V/V, which is set with resistors R_F and R_G . Equation 4 is used to size the resistors, R_F and R_G , to set the gain of the LMV722-Q1 to 49 V/V.

$$Gain = 1 + \frac{(R_F)}{(R_G)}$$
(4)

Choosing R_F as 57.6 $k\Omega$ and R_G as 1.2 $k\Omega$ provides a combination that equals roughly 49 V/V. Figure 27 shows the measured transfer function of the circuit shown in Figure 26.

8.2.3 Application Curve

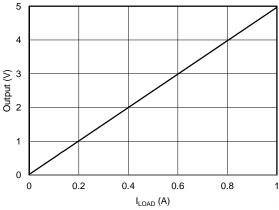


Figure 27. Low-Side, Current-Sense, Transfer Function

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9 Power Supply Recommendations

The LMV722-Q1 series is specified for operation from 2.2 V to 5.5 V (±1.1 V to ±2.75 V); many specifications apply from –40°C to +125°C. The section presents parameters that can exhibit significant variance with regard to operating voltage or temperature.

CAUTION

Supply voltages larger than 6 V can permanently damage the device; see the *Absolute Maximum Ratings* table.

Place 0.1-µF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, see the section.

9.1 Input and ESD Protection

The LMV722-Q1 incorporates internal ESD protection circuits on all pins. For input and output pins, this protection primarily consists of current-steering diodes connected between the input and power-supply pins. These ESD protection diodes provide in-circuit, input overdrive protection, as long as the current is limited to 10-mA, as stated in the *Layout Guidelines* table. Figure 28 shows how a series input resistor can be added to the driven input to limit the input current. The added resistor contributes thermal noise at the amplifier input and the value must be kept to a minimum in noise-sensitive applications.

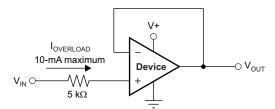


Figure 28. Input Current Protection

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10 Layout

10.1 Layout Guidelines

For best operational performance of the device, use good printed circuit board (PCB) layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and of op amp itself. Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
 - Connect low-ESR, 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for singlesupply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective
 methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground
 planes. A ground plane helps distribute heat and reduces electromagnetic interference (EMI) noise
 pickup. Make sure to physically separate digital and analog grounds, paying attention to the flow of the
 ground current. For more detailed information refer to, see Circuit Board Layout Techniques.
- In order to reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, crossing the sensitive trace perpendicular is much better as opposed to in parallel with the noisy trace.
- Place the external components as close to the device as possible. As illustrated in Figure 30, keeping RF and RG close to the inverting input minimizes parasitic capacitance on the inverting input.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.
- Cleaning the PCB following board assembly is recommended for best performance.
- Any precision integrated circuit can experience performance shifts resulting from moisture ingress into the
 plastic package. Following any aqueous PCB cleaning process, baking the PCB assembly is
 recommended to remove moisture introduced into the device packaging during the cleaning process. A
 low-temperature, post-cleaning bake at 85°C for 30 minutes is sufficient for most circumstances.

Product Folder Links: LMV722-Q1

10.2 Layout Example

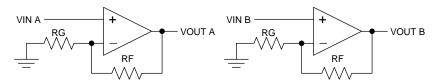


Figure 29. Schematic Representation for Figure 30

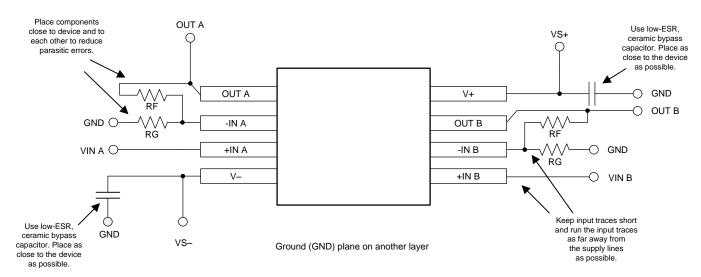


Figure 30. Layout Example



11 Device and Documentation Support

11.1 Documentation Support

11.1.1 Related Documentation

For related documentation see the following:

Circuit Board Layout Techniques

11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.4 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

11.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGE OPTION ADDENDUM

12-Jul-2017

PACKAGING INFORMATION

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Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
LMV722QDGKRQ1	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	R6EQ	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF LMV722-Q1:



PACKAGE OPTION ADDENDUM

12-Jul-2017

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NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





Α0	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV722QDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

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*All dimensions are nominal

Device	Device Package Type		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
LMV722QDGKRQ1	VSSOP	DGK	8	2500	366.0	364.0	50.0	

DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



DGK (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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